International TOR Rectifier

Series PVN012

HEXFET® Power MOSFET Photovoltaic Relay

Microelectronic Power IC Relay

Single Pole, Normally Open, 0-20V, 2.5A AC/ 4.5A DC

General Description

The PVN012 Series Photovoltaic Relay at 100 milliohms features the lowest possible on-state resistance in a miniature package — lower than a comparable reed relay.

The PVN012 is a single-pole, normally open solidstate relay. It utilizes a GenerationV HEXFET output switch, driven by an integrated circuit photovoltaic generator of novel construction. The output switch is controlled by radiation from a GaAlAs light emitting diode (LED) which is optically isolated from the photovoltaic generator.

These units exceed the performance capabilities of electromechanical relays in life, sensitivity, stable on-resistance, miniaturization, magnetic insensitivity and ruggedness. They are ideally suited for switching high currents or low level signals without distortion or injection of electrical noise.

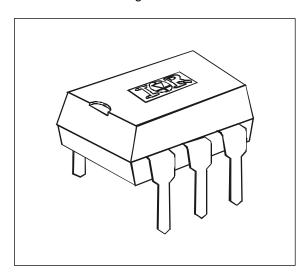
Series PVN012 Relays are packaged in a 6-lead molded DIP package with either through-hole or surface mount (gull-wing) terminals. They are available in standard plastic shipping tubes or on tape-and-reel. Please refer to part identification information opposite.

Applications

- Portable Electronics
- Programmable Logic Controllers
- Computers and Peripheral Devices
- Audio Equipment
- Power Supplies and Power Distribution
- Instrumentation

PVN012 Features

- 100mΩ On-Resistance ■
- GenV HEXFET output ■
- Bounce-free operation ■
- 2.5 4.5 Amp capacity ■
- Linear AC/DC operation ■
- 4,000 V_{RMS} I/O isolation
 - Solid-State reliability ■
- UL recognized and CSA certified ■



Part Identification

PVN012 through-hole PVN012S surface-mount

PVN012S-T surface-mount, Tape and Reel

Series PVN012 — HEXFET® Photovoltaic Relay

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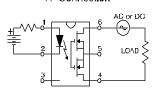
Electrical Specifications (-40°C \leq T_A \leq +85°C unless otherwise specified)

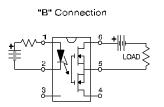
| INPUT CHARACTERISTICS | Limits | Units |
|---|-----------|-------|
| Minimum Control Current (see figure 1) | 3.0 | mA |
| Maximum Control Current for Off-State Resistance @ T _A = +25°C | 0.4 | mA |
| Control Current Range (Caution: current limit input LED, see figure 6) | 3.0 to 25 | mA |
| Maximum Reverse Voltage | 7.0 | V |

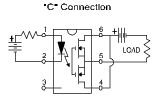
| OUTPUT CHARACTERISTICS | Limits | Units |
|---|------------------------|------------------|
| Operating Voltage Range | 0 to ±20 | V(DC or AC peak) |
| Maximum Continuous Load Current @ T _A =+40°C, 5mA Control (see figure 1) | | , , |
| A Connection | 2.5 | A (DC or AC) |
| B Connection | 3.0 | A (DC) |
| C Connection | 4.5 | A (DC) |
| Maximum Pulsed Load Current @T _A =+25°C, (100 ms @ 10% duty cycle) | | |
| A Connection | 6.0 | A (DC or AC) |
| Maximum On-State Resistance @T _A =+25°C, for 1A pulsed load, 5mA Control (see figure 4) | | |
| A Connection | 100 | |
| B Connection | 65 | mΩ |
| C Connection | 40 | |
| Minimum Off-State Resistance @ T _A =+25°C, ±16V _{DC} | 0.16 x 10 ⁸ | Ω |
| Maximum Off-State Leakage @T _A =+25°C, ±16V _{DC} (see figure 5) | 1.0 | mA |
| Maximum Turn-On Time @T _A =+25°C (see figure 7), for 1A, 20 V _{DC} load, 5mA Control | 5.0 | ms |
| Maximum Turn-Off Time @T _A =+25°C (see figure 7), for 1A, 20 V _{DC} load, 5mA Control | 0.5 | ms |
| Maximum Output Capacitance @ 20V _{DC} (see figure 2) | 300 | pF |

| GENERAL CHARACTERISTICS | | Limits | Units |
|--|-----------|-------------|-------|
| Minimum Dielectric Strength, Input-Output | | 4000 | VRMS |
| Minimum Insulation Resistance, Input-Output, @T _A =+25°C, 50%RH, 100V _{DC} | | 1012 | Ω |
| Maximum Capacitance, Input-Output | | 1.0 | pF |
| Maximum Pin Soldering Temperature (10 seconds maxir | mum) | +260 | |
| Ambient Temperature Range: | Operating | -40 to +85 | °C |
| | Storage | -40 to +100 | |

Connection Diagrams "A" Connection







Series PVN012 — HEXFET® Photovoltaic Relay

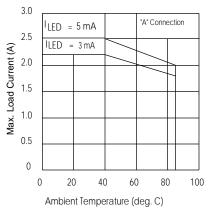
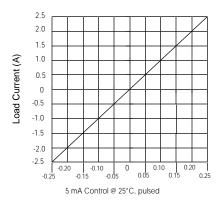


Figure 1. Current Derating Curves*



Connection "A" Voltage Drop (Vdd)

Figure 3. Linearity Characteristics

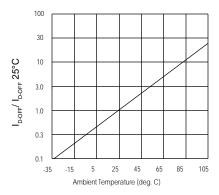
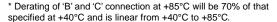


Figure 5. Typical Normalized Off-State Leakage



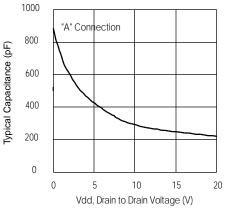


Figure 2. Typical Output Capacitance

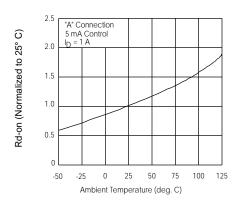


Figure 4. Typical Normalized On-Resistance

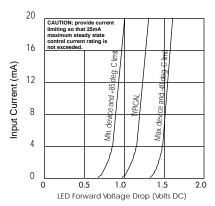
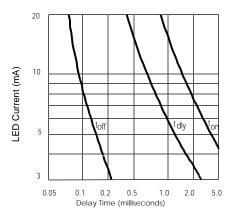


Figure 6. Input Characteristics (Current Controlled)

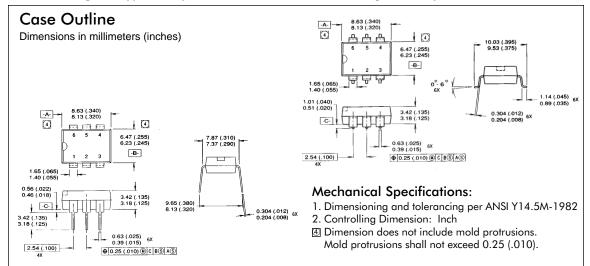


90%

John toff

Figure 7. Typical Delay Times

Figure 8. Delay Time Definitions



International Rectifier

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Data and specifications subject to change without notice. 9/96